

GBJ35B thru GBJ35G

Single Phase Glass Passivated Silicon Bridge Rectifier

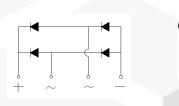
V_{RRM} = 100 V - 400 V I_O = 35 A

GBJ Package

Features

• Epoxy Resin material compliant with 94V-0 standards of UL Material Flammability Provisions

- Compliant with RoHS Provisions
- Single in-line DIP package, compact size
- · Low forward voltage, high forward current
- High surge current capability
- Types from 100 V to 400 V V_{RRM}
- · Small size, high heat-conducting performance
- Thermal welding performance: 260 °C/10 s
- Weight: 7.25 g (0.25 Oz)
- Not ESD Sensitive





Maximum ratings at T_A = 25 °C (ambient temperature), unless otherwise specified

| Parameter | Symbol | Conditions | GBJ35B | GBJ35D | GBJ35G | Unit |
|---------------------------|-------------------------|------------|------------|------------|------------|------|
| Repetitive peak reverse v | oltage V _{RRM} | | 100 | 200 | 400 | V |
| DC blocking voltage | V _{DC} | | 100 | 200 | 400 | V |
| Operating temperature | Tj | | -50 to 150 | -50 to 150 | -50 to 150 | °C |
| Storage temperature | T _{stg} | | -50 to 150 | -50 to 150 | -50 to 150 | °C |

Electrical characteristics at T_A = 25 °C, unless otherwise specified

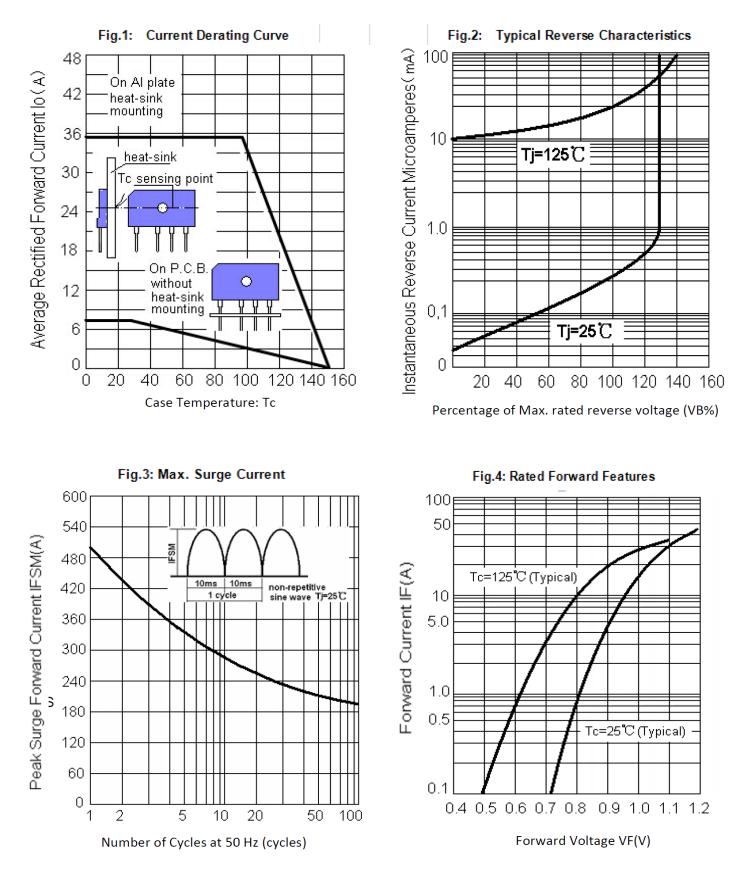
Resistive load, single phase, half sine wave, 60 Hz.

For capacitive load derate current by 20%.

| Parameter | Symbol | Conditions | GBJ35B | GBJ35D | GBJ35G | Unit |
|---|-------------------|---|--------------------|----------------------------|--------------------|------------------|
| Maximum average forward rectified current | Ι _Ο | T _C = 98 °C | 35 ⁽¹⁾ | 35 ⁽¹⁾ | 35 ⁽¹⁾ | А |
| | | T _A = 25 °C | 6.8 ⁽²⁾ | 6.8 ⁽²⁾ | 6.8 ⁽²⁾ | |
| Maximum forward surge current | I _{FSM} | 8.3 ms pulse width, single pulse sine-wave, rated load, $T_j = 25 \text{ °C}$ | 500 | 500 | 500 | A |
| Maximum forward voltage | V _F | I _F = 17.5 A | 1.05 | 1.05 | 1.05 | V |
| Max. reverse current leakage at | it I _R | T _A = 25 °C | 5 | 5 | 5 | μA |
| rated DC blocking voltage | | T _A = 125 °C | 500 | 500 | 500 | |
| Insulation strengthg (Lead wire to case) | V_{dis} | AC Voltage: 1 minute, current leakage < 1 mA | 2.5 | 2.5 | 2.5 | kV |
| Fusing feature | l ² t | 1ms ≤ t < 10ms, T _j =25 °C | 410 | 410 | 410 | A ² s |
| Thermal resistance | $R_{\Theta JA}$ | without heatsink | 28 (2) | 28 ⁽²⁾ | 28 ⁽²⁾ | °C/W |
| | $R_{\Theta JC}$ | with stated size heatsink | 1.0 ⁽¹⁾ | 1.0 ⁽¹⁾ | 1.0 ⁽¹⁾ | |
| Mounting torgue | TOR | | | 1.0 (0.8 Nm is recomended) | | Nm |

Remarks: (1) Install on PCB with stated size heat sink. In order to reach excellent heat dissipation performance, please coat thermal conductive sillica gel in moderation, use M3 screw to screw up. Recommended heatsink size: 19.0*19.0*7.6 cm.
(2) Install on PCB without heatsink.



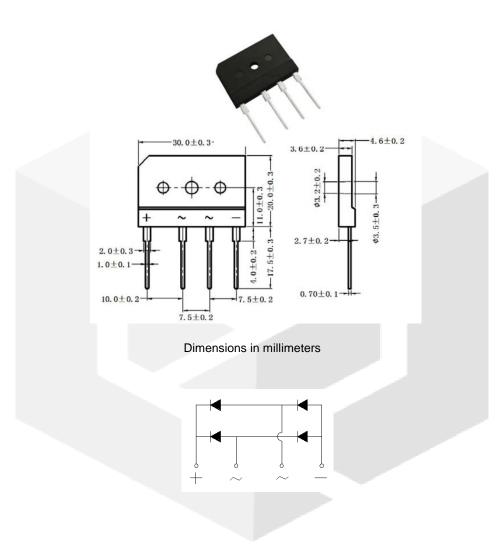






Package dimensions and terminal configuration

Product is marked with part number and terminal configuration.



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